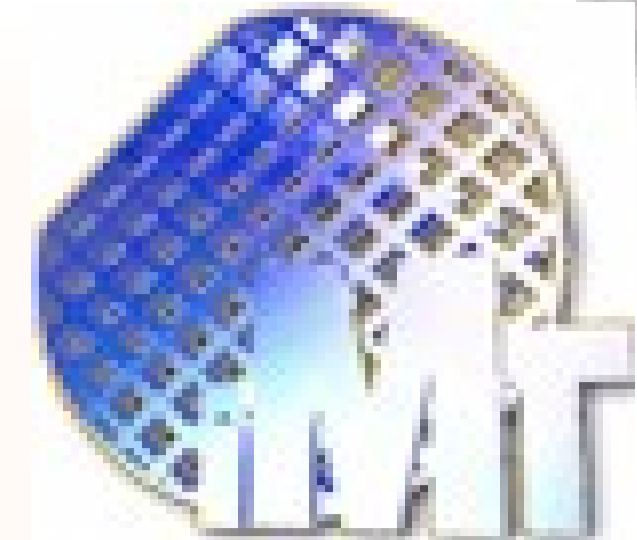


SOL-GEL NANOSTRUCTURED Al-DOPED ZnO COATINGS



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Abstract

Transparent and conducting thin ZnO films have been extensively studied due to potential applications in various fields e.g. flat panel displays, gas sensors, solar cell windows, surface acoustic wave devices, short wavelength light emitting devices, daylight-blind UV detectors[1]. In the literature data [2-3], various physical and chemical methods for obtaining the ZnO-based films are mentioned.

In the present work, mono- and multilayer Al doped ZnO coatings have been obtained by the sol-gel method on the silicon and glass supports; their structural and morphological characterization have been performed. The solutions were prepared from zinc acetate and aluminium nitrate in absolute ethanol in the presence of triethanolamine.

Structural and morphological evolutions of the coatings have been investigated by X-ray diffraction and Atomic force microscopy. After five layer depositions, the obtained coatings are polycrystalline with wurtzite type structure; the thickness of the coating is of 90 nm and the grain size between 20-40 nm. Fluorescence emission spectra indicate a decrease in the intensity of fluorescence emission bands with increasing number of deposition layers.

Systematic study performed allows finding most suitable chemical parameters for obtaining coatings with desired optical properties.

References

- [1] Z. L. Wang *Mat. Sci. Eng.* 2009, R 64 34, 33-71
- [2] T. Schuler; M. A. Aegerter *Thin Solid Films* 1999, 351, 125-131
- [3] P. Sagar; M. Kumar; R.M. Mehra *Solid State Communications* 2008, 47, 465-469

Experimental

Starting materials:

Precursors:

- Zinc acetate dihydrate (p.a.) $Zn(CH_3COO)_2 \cdot 2H_2O$ (ZAD)
- Aluminiumnitrat-nonahydrat- $Al(NO_3)_3 \cdot 9H_2O$ (ANN)
- absolute ethanol - CH_3CH_2OH
- Triethanolamine - $(CH_3CH_2OH)_3N$ (TEA)

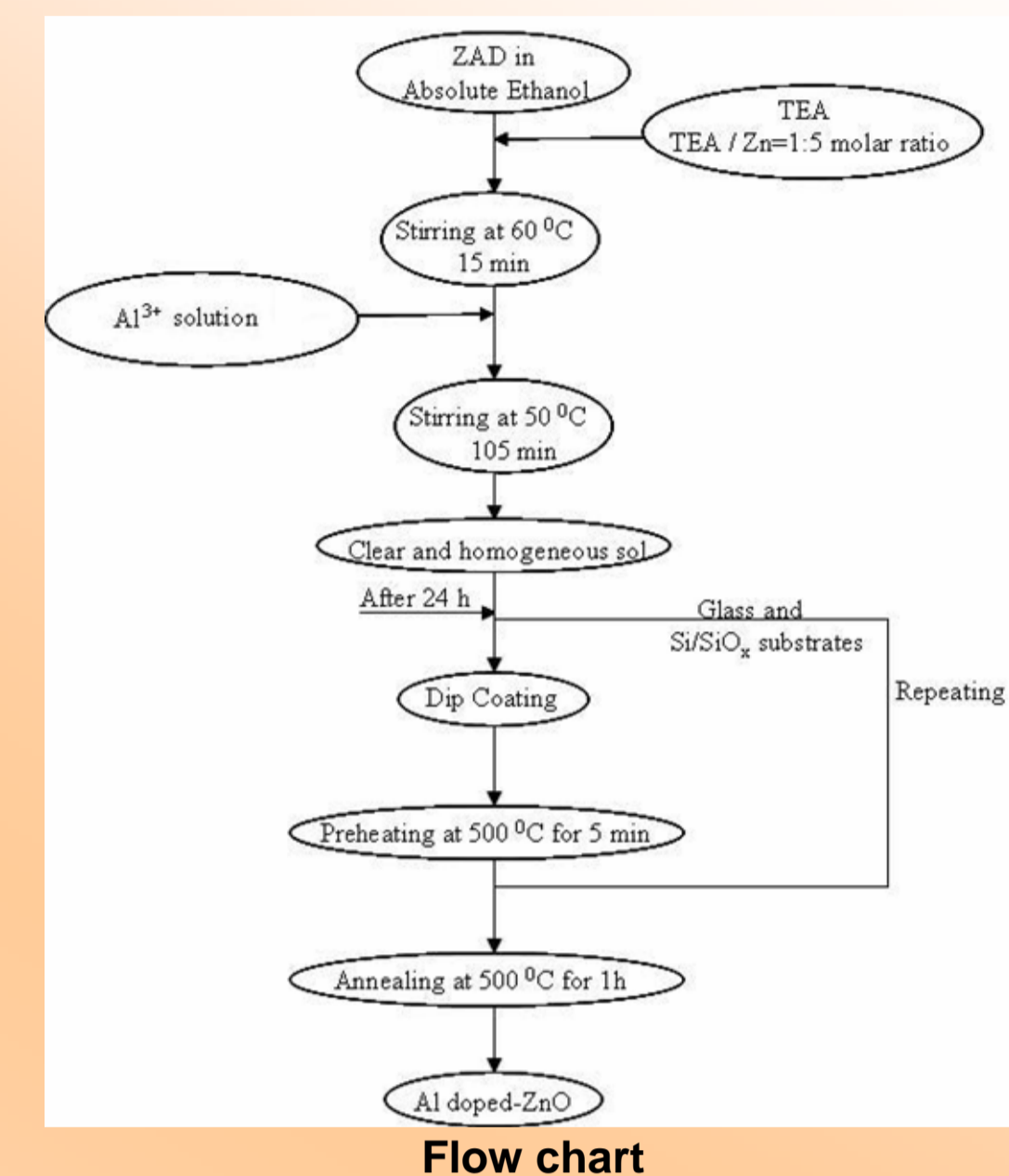
Initial Solutions:

- I-S-A_{0.5}ZO (0.05M of 95%ZAD and 5 %ANN in absolute ethanol and TEA with ZAD/TEA=5/1)
- II-S-A_{0.5}ZO (0.1M of 95%ZAD and 5%ANN in absolute ethanol and TEA with ZAD/TEA=5/1)
- II-S-A_{0.5}ZO (0.1M of 99.5%ZAD and 0.5%ANN in absolute ethanol and TEA with ZAD/TEA=5/1)

Obtained Coatings:

- I-A_{0.5}ZO-GF_n and I-A_{0.5}ZO-SF_n obtained from the I-S-A_{0.5}ZO solution on glass substrates (G) and on Si/SiO_x wafers (S)
- II-A_{0.5}ZO-SF_n and II-A_{0.5}ZO-SF_n obtained from the II-S-A_{0.5}ZO solution on the glass substrates (G) and the silicon wafers (S)
- II-A_{0.5}ZO-GF_n and II-A_{0.5}ZO-SF_n obtained from II-S-A_{0.5}ZO solution on the glass substrates (G) and the silicon wafers (S)

Where n = number of depositions



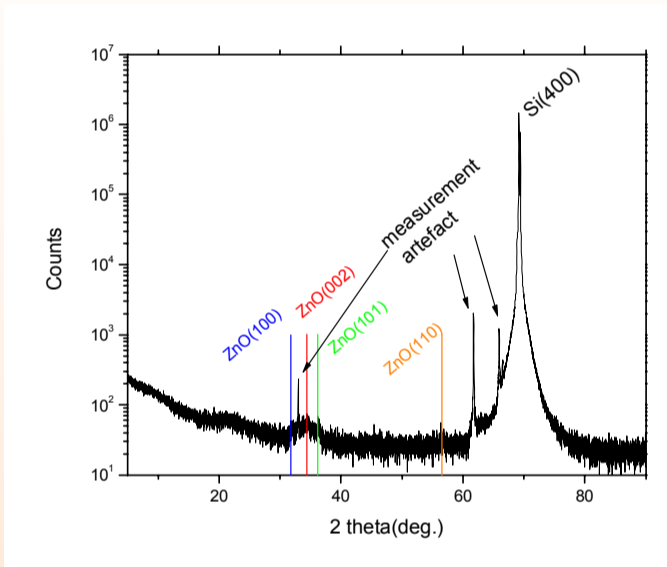
Methods of characterization

- X-Ray Diffraction analysis
- Atomic Force Microscopy (AFM)
- Scanning electron microscopy (SEM)
- Fluorescence Spectroscopy
- Spectroellipsometry (SE)

Results

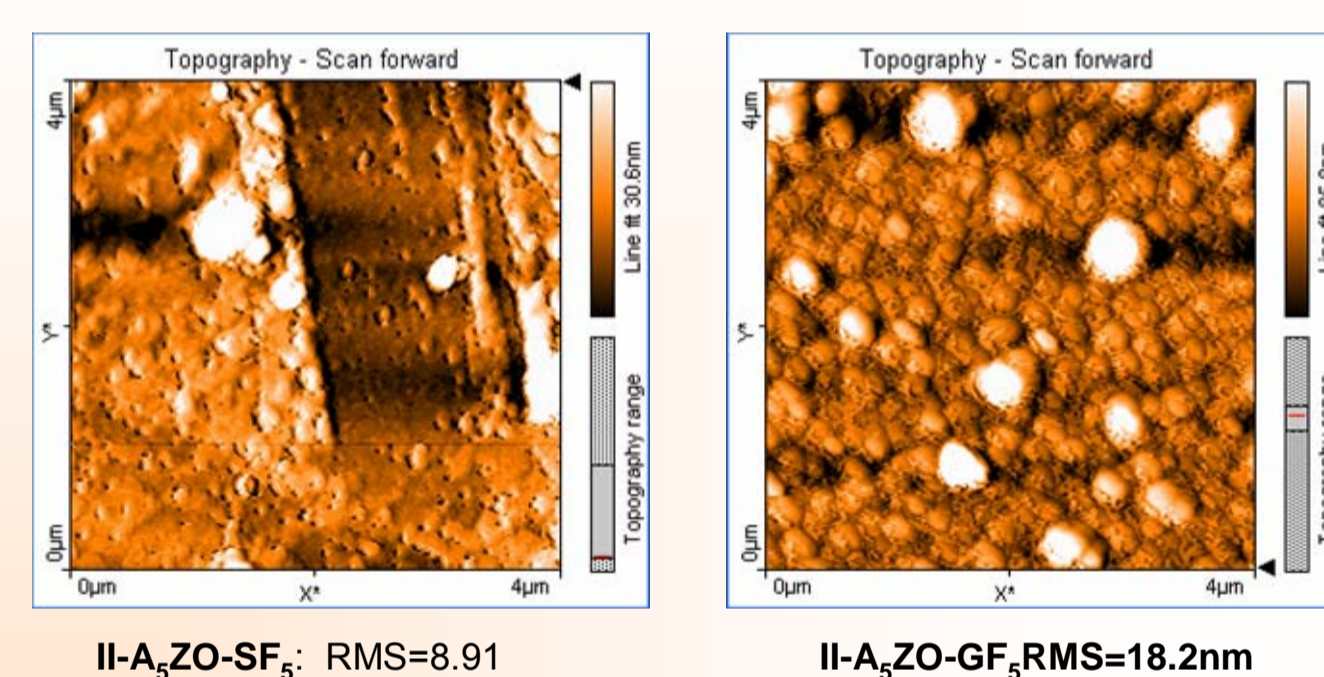
Influence of solution concentration on the coating morphology

X-Ray Diffraction



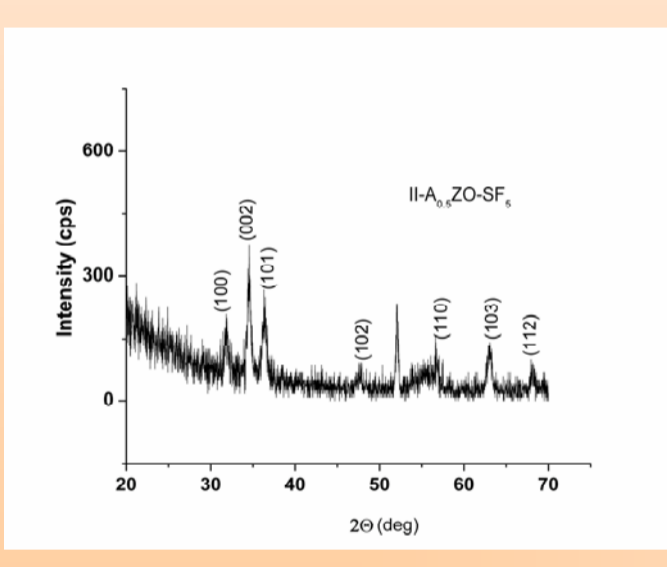
XRD pattern of the II-A_{0.5}ZO-SF₅ coating

Atomic Force Microscopy (AFM)

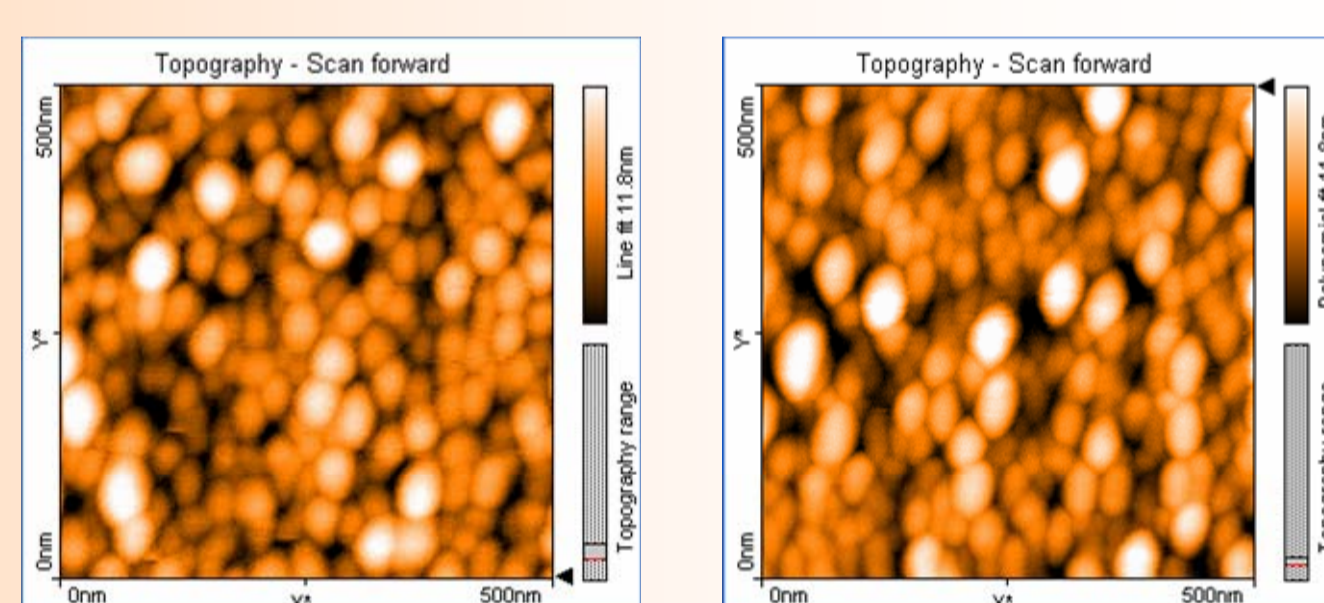


II-A_{0.5}ZO-SF₅ RMS=8.91

II-A_{0.5}ZO-GF₅ RMS=18.2nm



XRD pattern of the II-A_{0.5}ZO-SF₅ coating

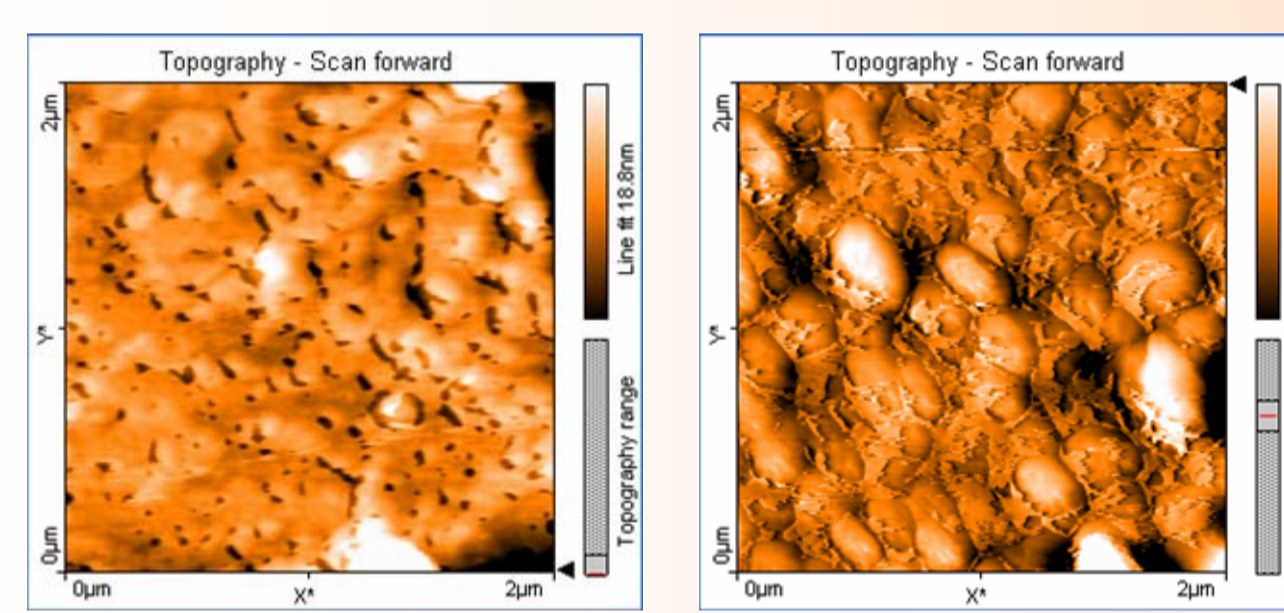


II-A_{0.5}ZO-SF₅ RMS=2.10nm

II-A_{0.5}ZO-GF₅ RMS=2.17nm

Influence of the substrate on the coating morphology and optical properties

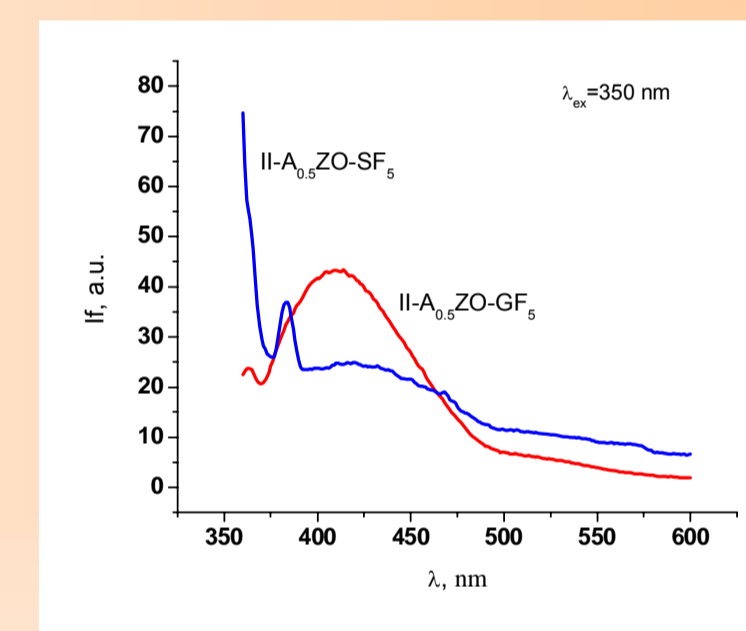
Atomic Force Microscopy (AFM)



2D AFM images of the coating obtained from II-S-A_{0.5}ZO solution after five depositions:

- II-A_{0.5}ZO-SF₅-coating on silicon substrate
- II-A_{0.5}ZO-GF₅-coating on glass substrate

Fluorescence Spectroscopy



Fluorescence emission spectra of the coatings obtained from the same initial solution and with the same number of depositions:
-on the glass substrate-II-A_{0.5}ZO-GF₅
-on the silicon wafer- II-A_{0.5}ZO-SF₅

Spectroellipsometry (SE)

Thickness and optical constant of the II-A_{0.5}ZO-GF₅ and II-A_{0.5}ZO-SF₅ coatings

II-A _{0.5} ZO like coating		Silicon	Glass
Thickness (nm)		29	68.7
Optical constants	n	1.38	1.80
	k	0.10	0.25

Influence of deposition number on the morphology and optical properties

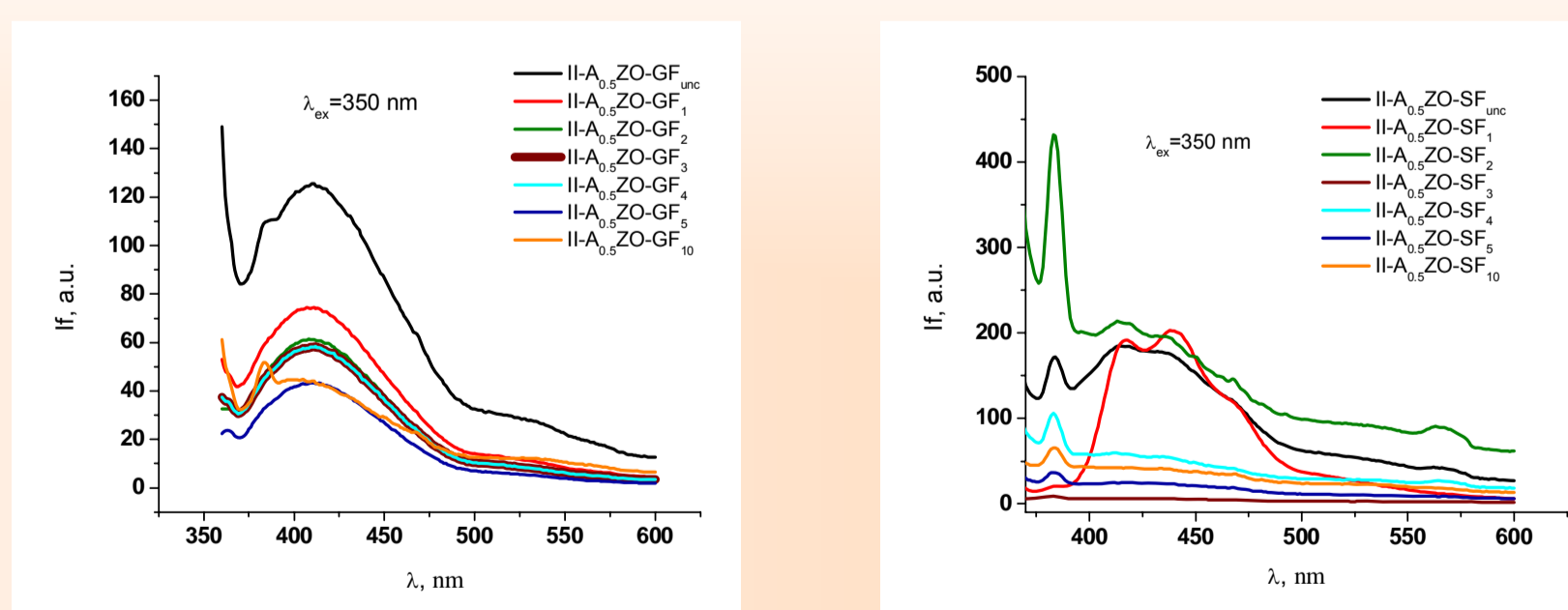
Spectroellipsometry (SE) results

Thickness and refractive index calculated from SE data

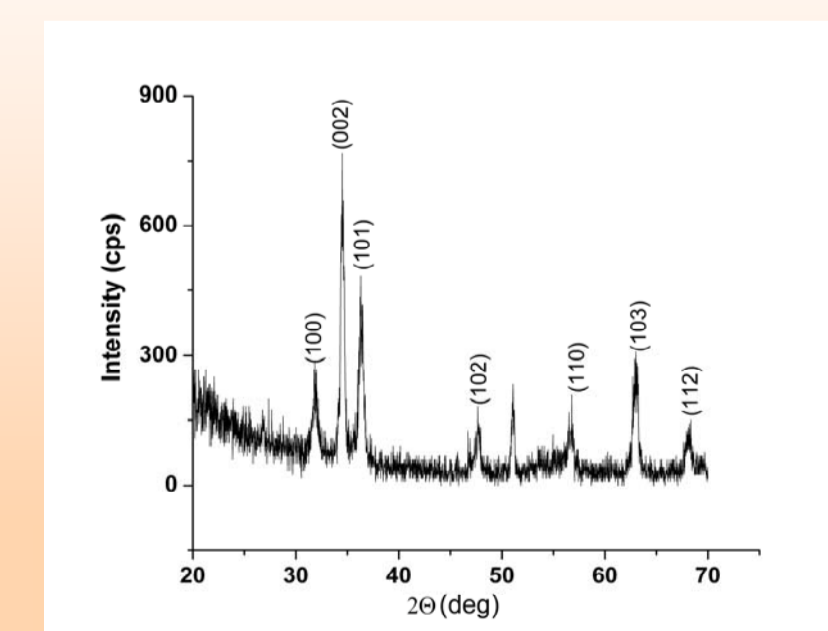
Sample	Thickness (nm)	Refractive index - n
*I-A _{0.5} ZO-SF _{unc}	11.54	1.16
I-A _{0.5} ZO-SF ₁	14.70	1.43
I-A _{0.5} ZO-SF ₂	6.3	1.47
I-A _{0.5} ZO-SF ₃	94.5	1.51
I-A _{0.5} ZO-SF ₄	50.5	1.51

*I-A_{0.5}ZO-SF_{unc} as-prepared coating

Fluorescence spectra of the II-A_{0.5}ZO-GF₁₋₁₀ and II-A_{0.5}ZO-SF₁₋₁₀ coatings



X-ray Diffraction of II-A_{0.5}ZO-SF₁₀



Conclusions

- ✓ Mono- and multilayer Al-doped ZnO coatings on the glass and silicon substrates have been obtained by dip coating sol-gel method .
- ✓ For the same deposition number , chemical composition and concentration of the precursor solutions affects the crystallization degree of the Al-doped ZnO coatings.
- ✓ Thinner and porous coatings with lower refractive indices are obtained on the SiO_x/Si wafers compared to those deposited on the glass substrate.
- ✓ After five layers deposition on the SiO_x/Si wafers, the Al-doped ZnO coatings are crystalline with a wurtzite structure.
- ✓ Fluorescence emission spectra of the studied samples are influenced by the precursor solutions, used substrates and number of depositions.

ACKNOWLEDGEMENTS

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